# Revisiting Tc-Structure Trends in Cuprate Superconductors using Materials Informatics

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High-temperature superconducting cuprates have the potential to be transformative in a wide range of energy applications. However, increasing the critical temperature, particularly of single-layer cuprates, remains an important goal. In this work we look at the corpus of historical data about cuprates and re-examine how their structures are related to their critical temperatures. The available data is highly clustered and no single database contains all the features of interest to properly examine trends. To work around these issues we employ a linear calibration approach that allows us to utilise multiple data sources – combining fine resolution data for which the critical temperature is unknown with coarse resolution data where it is known. The hybrid data set is used to explore the trends in critical temperature with the apical and in-plane copper-oxygen distances. We show that large regions of the materials space have yet to be explored and highlight how novel experiments relying on nano-engineering of the crystal structure may enable us to explore such new regions. Based on the trends identified we propose that single layer Bi-based cuprates are good candidate systems for such experiments.

Since the discovery of high-temperature superconductivity (HTS) in cuprate materials in 1986 significant amounts of research has been devoted to understanding, tuning/doping, and growing new cuprates in order to optimise their properties – both their critical transition temperatures (Tc) and other important properties such as the coherence length of the superconducting charge carriers. From these efforts several structurefunction relationships for HTS in cuprates are now well established in the literature [1, 2]. The most important factors to optimise for increasing Tc are believed to be: i) The concentration of charge carriers in the conduction planes, ii) The nature of bonding in the chargereservoir layers, iii) The in-plane Cu-O distance, and iv) The apical Cu-O distance (Here we do not consider electron-doped superconductors without apical oxygens i.e. those adopting a T' Structure).

Such relationships provide qualitative understanding and insight into the nature of superconductivity in these systems. Unfortunately, the consolidation of these trends into satisfactory quantitative theories for HTS in cuprates remains a challenge. In the mean time the lack of a mechanistic theory coupled with the potential availability of large amounts of data and high impact applications has driven researchers towards data-driven phenomenological approaches i.e. Machine Learning. Thus far, most work in this area has focused on building models that predict Tc [3, 4]. The hope is that such models may enable the discovery of new families of high-temperature superconductors. However, questions exist about whether such approaches will actually be fruitful when tested experimentally as the evaluation metrics used are often not reflective of real materials discovery workflows [5]. A less explored but similar avenue is how materials informatics approaches

can be used in conjunction with careful physical insights to probe our understanding of systems already known to display superconductivity [6]. It is this avenue of enquiry we pursue in this work.

The principle data source for this work is the Su-perCon database compiled and distributed by the Japanese National Institute for Material Science. Whilst SuperCon records the critical temperatures of an extensive range of superconducting materials the information available for each composition is minimal – structural information is only available for a small proportion of the entries and is limited to the lattice parameters when available. Unfortunately it is the common structure shared between different cuprates, characterised by the apical and in-plane distances of the superconducting CuO<sub>2</sub> planes, that is interesting for examining trends.

Whilst the lattice parameters can be determined relatively easily via x-ray diffraction, directly measuring the atomic positions to determine the apical and inplane distances typically involves much more costly neutron diffraction experiments. Fortunately, many cuprate structures are already recorded in the Inorganic Crystal Structure Database (ICSD) [7], although the critical temperatures of these materials are not recorded limiting their utility for studying Tc-Structure trends. To work around this we attempt to obtain estimates for the apical and in-plane distances from knowledge of just the lattice parameters.

For cuprates the a-lattice parameter is closely related to the in-plane distance. Assuming that the CuO<sub>2</sub> planes are approximately square planar the in-plane distance can be estimated as a/2 for tetragonal phases and  $a/2\sqrt{2}$  for octehedral phases.

Whilst the c-lattice parameter is often considered as a proxy for the apical distance there is actually little correlation between the two – the c-lattice parameter also depends on the thickness of the charge-reservoir

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Figure 1. Figures **A-D** show the trends between the critical temperature and the apical and in-plane distances stratified by the number of  $\text{CuO}_2$  planes and cation type. The red circled regions highlight materials containing La that are flagged as being anomalous to the general trends. The green circled region in **B** highlights that the trend of Tc increasing with apical distance is only apparent due to Hg and Tl-based materials with high apical distances – as such it may be correlation rather than causation. The linear trend lines in **D** are fitted having reweighed families according to their abundance. The materials containing La, circled in red, are excluded from the one-layer trend line. The offset between trend lines highlights how Tc appears to increase with the number of  $\text{CuO}_2$  planes. **E** shows the variation of Tc with the apical and in-plane distances. The orange circle highlights a large void that hasn't been explored. This region might be accessible with VAN films based on  $\text{Bi}_2\text{Sr}_2\text{CuO}_{6+x}$ .

layer which varies significantly between different families. Consequentially, to estimate the apical distances each family has to be treated independently. The simplest approach, adopted here, is the construction of linear calibration models on reference data, collated from ICSD, that relate the a and c-lattice parameters to the apical distance. These calibration models were then used to estimate the apical and in-plane distances for materials in *SuperCon* using their lattice parameters.

Beyond the apical and in-plane distances there are other important factors known to correlate with high Tc. Unfortunately, these are typically harder to quantify e.g. achieving optimal oxygen-doping is necessary to maximise Tc. However, materials in *SuperCon* are commonly reported with unknown oxygen concentrations. Generally, we are only interested in the trends between materials that have been characterised in optimally oxygen doped states. To determine such materials we perform k-means clustering on the data and then take the top 20% of each cluster by Tc - here high Tc is used as a heuristic for optimal oxygen-doping. Stratifying the remaining data set into different sub-groups we observe the following trends:

- 1. There exists a group of La containing cuprates with Tc ~40 K that deviate from the general trends seen amongst other materials (Circled in red in Figures 1A-D).
- 2. If materials are differentiated according to the number of  $\text{CuO}_2$  planes in the unit cell there is a clear separation between the different groups (Figures 1C and 1D). The observed increases in Tc with the number of planes are well understood considering intralayer interactions between  $\text{CuO}_2$  planes [8].
- 3. Whilst grouping by the number of  $CuO_2$  planes emphasises a strong positive correlation observed between Tc and the apical distance (Figure 1D), grouping materials via the main cation casts doubts on the generality of this trend. Stratifying shows that the trend only appears due to the existence of multiple Hg and Tl families with high apical distances (Circled in green in Figure 1B).
- 4. The apparent optimum in-plane distance for Hg and Tl-based cuprates is ~1.92 Å (Figure 1C). However, Rare Earth based (RE) materials show

very little variation in Tc as the in-plane distance changes. Bi-based materials show a slight increase as the in-plane distance approaches 1.92 Å but it is not apparent whether the same drop off in Tc as seen in Hg and Tl-based materials would be seen if the in-plane distance was increased beyond 1.92 Å. Indeed, the increase in Tc could instead be attributed to changes in the multi-layer structure between  $Bi_2Sr_2CuO_{6+x}$  and  $Bi_2Sr_2CaCu_2O_{8+x}$  type materials suggesting that there may be no strong dependence on the in-plane distance.

Figure 1E shows that large areas of the apical/inplane materials space remain unexplored (Circled in orange in Figure 1E). Past efforts have only been able sample in small regions around known systems due to the limitations of perturbing systems with mechanical and chemical (via atomic substitutions and doping) pressures. A key limitation is that due to Poisson effects such methods influence both the a and clattice parameters preventing the exploration of trends in a one-factor-at-a-time manner. Recently, new experiments have shown that it is possible to tune the a and c-lattice parameters independently allowing for unexplored regions of the materials space to be investigated [9, 10]. The vertically aligned nanocomposite (VAN) approach employed is of particular interest as it led to enhanced Tcs of 50 K and 120 K in nano-engineered  $La_2CuO_{4-\delta}$  films relative to 40 K in the bulk (These points are shown in Figure 1E). However, the enhanced behaviour is localised to interfacial regions in the composite making direct measurement of the atomic positions difficult. Hence to check whether these enhancements are in agreement with the trend that Tc increases with apical distance we estimate the apical distances for the two samples obtaining values of 2.42 Å and 2.56 Å respectively. These values are higher than in bulk  $La_2CuO_{4-\delta}$  providing weak evidence that the trend may be valid beyond Hg and Tl-based systems.

The major conclusions we draw for future work are that; i) The inability to conduct one-factor-at-a-time experiments on cuprates has made it much harder to establish causation vs correlation in Tc-Structure trends. Novel experimental approaches, such as VAN, may be helpful to address this shortcoming by allowing us to probe unexplored regions of the apical/in-plane materials space. Of particular interest for 3D strain engineering are  $Bi_2Sr_2CuO_{6+x}$  systems as they appear to have only a weak dependence on the in-plane distance. Consequentially, any observed changes in Tc can be attributed to the induced changes in the apical distance. ii) Here the limitations of our calibration based approach mean that we can only undertake qualitative rather than quantitative/predictive analysis. More systematic integration and novel data mining efforts [11] are desirable to improve superconductivity databases. Consolidating the vast amount of information available in the literature into a comprehensive source, containing critical temperatures alongside atomic structures, would facilitate the improved application of materials informatics approaches.

## METHODS

#### Estimation of the apical distance in cuprates

The variation in the apical distance within families is due to the chemical pressure that arises from doping. The simplest model is that the pressure imparts a uniform stress parallel to the c axis that strains the material. If the total strains are in the Hookean regime the strain along the c-axis should then be directly proportional to the strain in the apical distance - the implication being that we can approximate the materials' layered structure with hypothetical slabs of constant Young's modulus. The strains along a and c are also related by the Poisson effect therefore the minimal calibration model for the apical distances,  $\hat{d}_{\rm apical}$ , that also includes this effect is:

$$\hat{d}_{\text{apical}} = \alpha c + \beta a + \gamma \tag{1}$$

Where  $\alpha, \beta$  and  $\gamma$  are the parameters of the calibration model that need to be fitted for each family. A robust linear model was used to reduce the affect of outliers [12]. Models were fitted for the following families: La214 (T), Y123, RE123, Y124, RE124, Tl1201, Tl1212, Tl1223, Tl2201, Tl2212, Hg1201, Hg1212, Hg1223, Hg2212, Bi2201, and Bi2212 (Explanation of standard four-digit notation available in [13]). To increase the amount of reference available data both neutron and x-ray structures recorded in ICSD were used - ideally we would avoid x-ray structures as the oxygen positions can be effected by systematic errors. However, here we believe the increased abundance and diversity of reference data out-weights this potential loss of accuracy.

# Estimation of the apical distance in VAN systems

In [9] a Tc of 50K and a and c-lattice parameters of 3.79-3.76 Å and 13.20-13.28 Å are reported for the La<sub>2</sub>CuO<sub>4- $\delta$ </sub>/LaCuO<sub>3</sub> (c-214/a-113) interfacial region. The presence of domain matching in the structure suggests a uniform stress along c therefore the apical distance can be estimated using the linear calibration model for the La214 (T) family. This gives an estimate of 2.40-2.43 Å for the apical distance.

In [10] a weak magnetic signature for superconductivity at 120K is reported for a c-aligned La<sub>2</sub>CuO<sub>4- $\delta$ </sub>/ aaligned La<sub>2</sub>CuO<sub>4- $\delta$ </sub> (c-214/a-214) interface. Here there is La-block matching at the interface, rather than domain matching, suggesting a non-uniform stress. The La-block is believed to be 4.00 ± 0.01 Å at the interface - much larger than the average of 3.67 Å for the ICSD La214 (T) reference data. As this estimate requires a large degree of extrapolation we cannot justify a linear model. Instead we derive an estimate for the apical distance from considering the offset from the top of the La-block to the apical oxygen. This offset is strongly peaked around 0.56 Å giving an estimate of 2.56 Å with a 90% confidence interval of 2.51-2.62 Å.

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